

(19) World Intellectual Property
Organization
International Bureau



(43) International Publication Date
23 June 2005 (23.06.2005)

PCT

(10) International Publication Number
WO 2005/057677 A1

(51) International Patent Classification⁷: **H01L 51/30**,
C08G 61/12

(74) Agent: **OHIE, Kunihisa**; Ohie Patent Office,
Selva-Ningyocho 6F, 14-6, Nihonbashi-Ningyocho
2-chome, Chuo-ku, Tokyo 103-0013 (JP).

(21) International Application Number:
PCT/JP2004/018668

(81) Designated States (*unless otherwise indicated, for every
kind of national protection available*): AE, AG, AL, AM,
AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN,
CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI,
GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, KE, KG,
KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG,
MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH,
PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN,
TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.

(22) International Filing Date: 8 December 2004 (08.12.2004)

(25) Filing Language: English

(26) Publication Language: English

(30) Priority Data:
2003-410097 9 December 2003 (09.12.2003) JP
60/529,106 15 December 2003 (15.12.2003) US

(84) Designated States (*unless otherwise indicated, for every
kind of regional protection available*): ARIPO (BW, GH,
GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM,
ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM),
European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI,
FR, GB, GR, HU, IE, IS, IT, LT, LU, MC, NL, PL, PT, RO,
SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN,
GQ, GW, ML, MR, NE, SN, TD, TG).

(71) Applicant (*for all designated States except US*): **SHOWA
DENKO K.K.** [JP/JP]; 13-9, Shiba Daimon 1-chome, Mi-
nato-ku, Tokyo 105-8518 (JP).

(72) Inventors; and

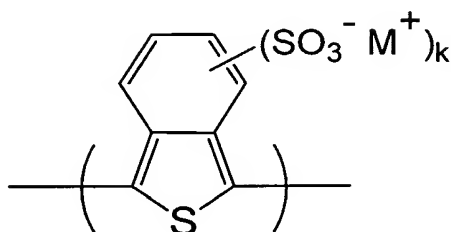
(75) Inventors/Applicants (*for US only*): **KOYAMA, Tamami**
[JP/JP]; c/o Corporate R & D Center, Showa Denko K.K.,
1-1, Ohnodai 1-chome, Midori-ku, Chiba-shi, Chiba 267-
0056 (JP). **KONDO, Kunio** [JP/JP]; c/o Corporate R & D
Center, Showa Denko K.K., 1-1, Ohnodai 1-chome, Mi-
dori-ku, Chiba-shi, Chiba 267-0056 (JP).

Published:

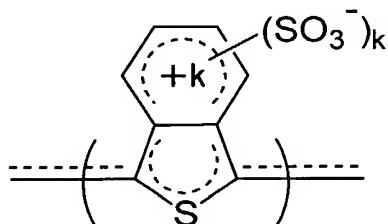
- with international search report
- before the expiration of the time limit for amending the
claims and to be republished in the event of receipt of
amendments

[Continued on next page]

(54) Title: POLYMER FOR ANODE BUFFER LAYER, COATING SOLUTION FOR ANODE BUFFER LAYER, AND OR-
GANIC LIGHT EMITTING DEVICE



(1)



(2)

(57) Abstract: The present invention relates to:
a polymer for an anode buffer layer in an organic
light emitting device comprising a self-doping
conductive polymer having a pH value of 3 to 7
in a 1% by mass aqueous solution, the polymer
containing monomer unit (s) represented by
the following formula (1) and/or (2) wherein M⁺
represents a hydrogen ion, an alkali metal ion,
or a quaternary ammonium ion, k represents 1
or 2, +k represents a positive charge number,
and a hydrogen atom in the aromatic ring may
be replaced by a substituent, an anode buffer
layer coating solution comprising the polymer,
and an organic light emitting device comprising
an anode buffer layer using the polymer. The
polymer of the present invention can overcome
the problem of deterioration of light emitting
layer due to extrinsic dopant.



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